

L Number	Hits	Search Text	DB	Time stamp
49	42	blast\$3 same incorporat\$7 near9 (surface substrate) near9 (particle particulate corundum silica abrasive (silicon near3 carbide))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 16:27
50	0	blast\$3 same (irregulat\$4 rough\$4) near9 incorporat\$7 near9 (surface substrate) near9 (particle particulate corundum silica abrasive (silicon near3 carbide))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 16:28
51	1	(irregulat\$4 rough\$4) near9 incorporat\$7 near9 blast\$3 near9 (particle particulate corundum silica abrasive (silicon near3 carbide))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 16:33
52	100	incorporat\$7 near9 blast\$3 near9 (particle particulate corundum silica abrasive (silicon near3 carbide))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 16:29
53	80	blast\$3 near9 incorporat\$7 near3 (particle particulate corundum silica abrasive (silicon near3 carbide))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 16:37
54	309	(irregulat\$4 rough\$4) near9 incorporat\$7 near3 (particle particulate corundum silica abrasive (silicon near3 carbide))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 16:33
55	309	(irregulat\$4 rough\$4) near9 incorporat\$7 near3 (particle particulate corundum silica abrasive abrading (silicon near3 carbide))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 16:34
56	9	((irregulat\$4 rough\$4) near9 incorporat\$7 near3 (particle particulate corundum silica abrasive abrading (silicon near3 carbide))) same (blast\$3 pressure)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 16:34
57	57	(blasing abrading) near9 incorporat\$7 near3 (particle particulate corundum silica abrasive (silicon near3 carbide))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 16:38
58	57	(blasing abrading sandblasing) near9 incorporat\$7 near3 (particle particulate corundum silica abrasive (silicon near3 carbide))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 16:40
59	17	(blasing abrading sandblasing) near9 incorporat\$7 near3 surface	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 16:41
60	0	(blasing sandblasing) near9 incorporat\$7 near3 (particle particulate corundum silica abrasive (silicon near3 carbide))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 16:48

61	0	(blasina sandblasing) and incorporate\$7 near3 (particle particulate corundum silica abrasive (silicon near3 carbide))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 16:44
62	3009	incorporate\$7 near3 (particle particulate corundum silica abrasive abrading (silicon near3 carbide)) near9 surface	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 16:43
63	5700	incorporate\$7 near9 (particle particulate corundum silica abrasive abrading (silicon near3 carbide)) near9 surface	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 16:43
64	0	(incorporate\$7 near9 (particle particulate corundum silica abrasive abrading (silicon near3 carbide)) near9 surface) and (blasina sandblasing)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 16:43
65	1	(blasina sandblasing) and (particle particulate corundum silica abrasive (silicon near3 carbide)) near9 surface near9 irregular\$8	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 16:45
66	2	(blasina sandblasing) and (particle particulate corundum silica abrasive (silicon near3 carbide)) near9 irregular\$8	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 16:46
67	0	(blasina sandblasing) and (particle particulate corundum silica abrasive abrading (silicon near3 carbide)) near9 imbed\$6	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 16:49
68	25	(blasina sandblasing) same (particle particulate corundum silica abrasive (silicon near3 carbide))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 16:49
69	1684	(blasina sandblasting) same (particle particulate corundum silica abrasive (silicon near3 carbide))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 16:49
70	32	(blasina sandblasting) and (particle particulate corundum silica abrasive abrading (silicon near3 carbide)) near9 imbed\$6	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 17:29
71	0	(blasina sandblasting) and (particle particulate corundum silica abrasive abrading (silicon near3 carbide)) near9 imbed\$6 near9 (rough\$9 irregular\$6) near9 (nanometer nm micron mil)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 16:53
72	0	(blasina sandblasting) and (particle particulate corundum silica abrasive abrading (silicon near3 carbide)) near9 imbed\$6 and (rough\$9 irregular\$6) near9 (nanometer nm micron mil)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 16:54

73	0	(blasng sandblasting) and (particle particulate corundum silica abrasive abrading (silicon near3 carbide)) near9 (nanometer nm micron mil) near9 imbed\$6	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 16:54
74	31	(particle particulate corundum silica abrasive abrading (silicon near3 carbide)) near9 imbed\$6 near9 (blasng sandblasting pressure)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 17:29
75	29	((particle particulate corundum silica abrasive abrading (silicon near3 carbide)) near9 imbed\$6 near9 (blasng sandblasting pressure)) not ((blasng sandblasting) and (particle particulate corundum silica abrasive abrading (silicon near3 carbide)) near9 imbed\$6)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 17:03
76	33	(particle particulate corundum silica abrasive abrading grit (silicon near3 carbide)) near9 imbed\$6 near9 (blasng sandblasting pressure jet)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 17:13
77	31	((particle particulate corundum silica abrasive abrading grit (silicon near3 carbide)) near9 imbed\$6 near9 (blasng sandblasting pressure jet)) not ((blasng sandblasting) and (particle particulate corundum silica abrasive abrading (silicon near3 carbide)) near9 imbed\$6)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 17:13
78	305	427/275.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 17:29
79	1	(particle particulate corundum silica abrasive abrading (silicon near3 carbide)) near9 imbed\$6 and 427/275.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 17:30
80	205	(particle particulate corundum silica abrasive abrading (silicon near3 carbide)) near9 imbed\$6 and (blasng sandblasting jet)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 17:32
81	22	(particle particulate corundum silica abrasive abrading (silicon near3 carbide)) near9 imbed\$6 same (blasng sandblasting jet)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 17:32
82	32	(particle particulate corundum silica abrasive abrading (silicon near3 carbide)) near9 imbed\$6 and (blasng sandblasting)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 17:31
83	32	(particle particulate corundum silica abrasive abrading (silicon near3 carbide)) near9 imbed\$6 and (blasng sandblasting)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 17:35
84	18	((particle particulate corundum silica abrasive abrading (silicon near3 carbide)) near9 imbed\$6 same (blasng sandblasting jet)) not ((blasng sandblasting) and (particle particulate corundum silica abrasive abrading (silicon near3 carbide)) near9 imbed\$6)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 17:33

89	40	(particle particulate corundum silica abrasive abrading (silicon near3 carbide)) near9 imbed\$6 same (blast\$3 sandblast\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 17:36
90	44	(particle particulate corundum silica abrasive abrading grit (silicon near3 carbide)) near9 imbed\$6 same (blast\$3 sandblast\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 17:43
91	23	((particle particulate corundum silica abrasive abrading grit (silicon near3 carbide)) near9 imbed\$6 same (blast\$3 sandblast\$3)) not ((blasing sandblasting) and (particle particulate corundum silica abrasive abrading (silicon near3 carbide)) near9 imbed\$6)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 17:36
92	44	(particle particulate corundum silica abrasive abrading grit (silicon near3 carbide)) near9 imbed\$6 same (blast\$9 sandblast\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 17:44
93	0	((particle particulate corundum silica abrasive abrading grit (silicon near3 carbide)) near9 imbed\$6 same (blast\$9 sandblast\$3)) not (((particle particulate corundum silica abrasive abrading grit (silicon near3 carbide)) near9 imbed\$6 same (blast\$3 sandblast\$3)) not ((blasing sandblasting) and (particle particulate corundum silica abrasive abrading (silicon near3 carbide)) near9 imbed\$6)) ((particle particulate corundum silica abrasive abrading grit (silicon near3 carbide)) near9 imbed\$6 same (blast\$3 sandblast\$3)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/18 17:44